

# **New Phases in Disordered Quantum Systems**

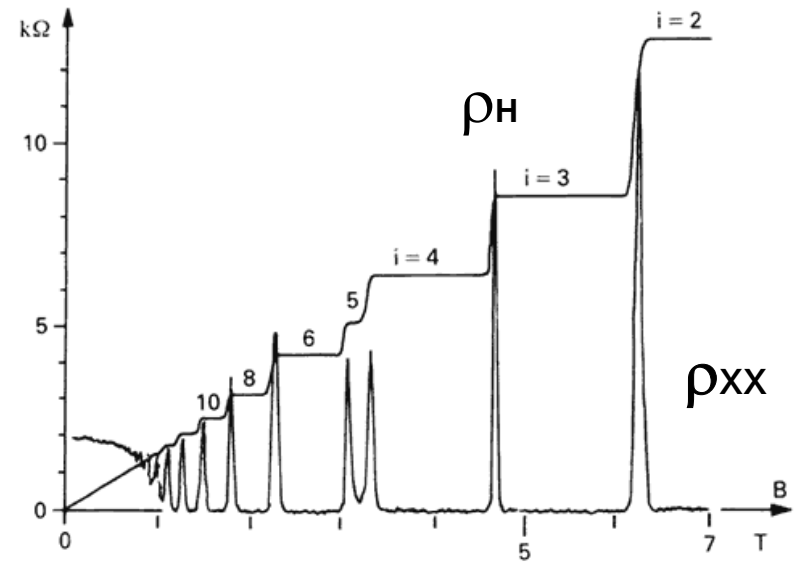
# DISORDER: yuch!!



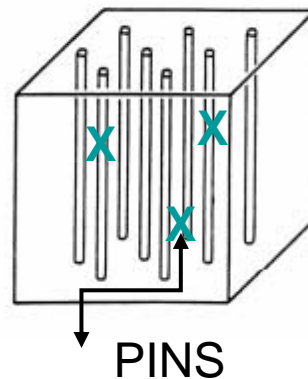
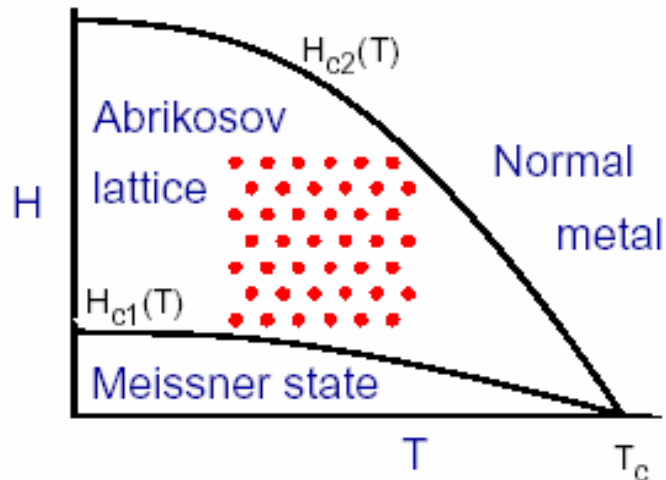
## NEW PHENOMENA

### Quantum Hall Effect

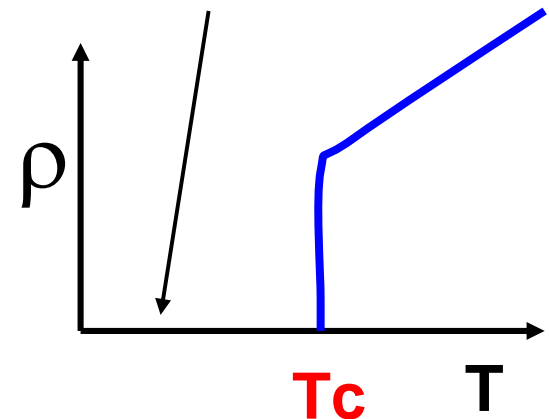
Quantization to 1 part in  $10^8$   
ONLY if some disorder in sample



### Superconductivity with vortices



$\rho=0$  only if vortices are pinned



# T=0 Quantum Phase Transitions

Qualitative change of the ground state wave function  
by tuning a parameter:

Trapped atomic gases:

- density
- periodic potential
- interactions

Solid State Systems:

- density
- magnetic field
- pressure
- **disorder**

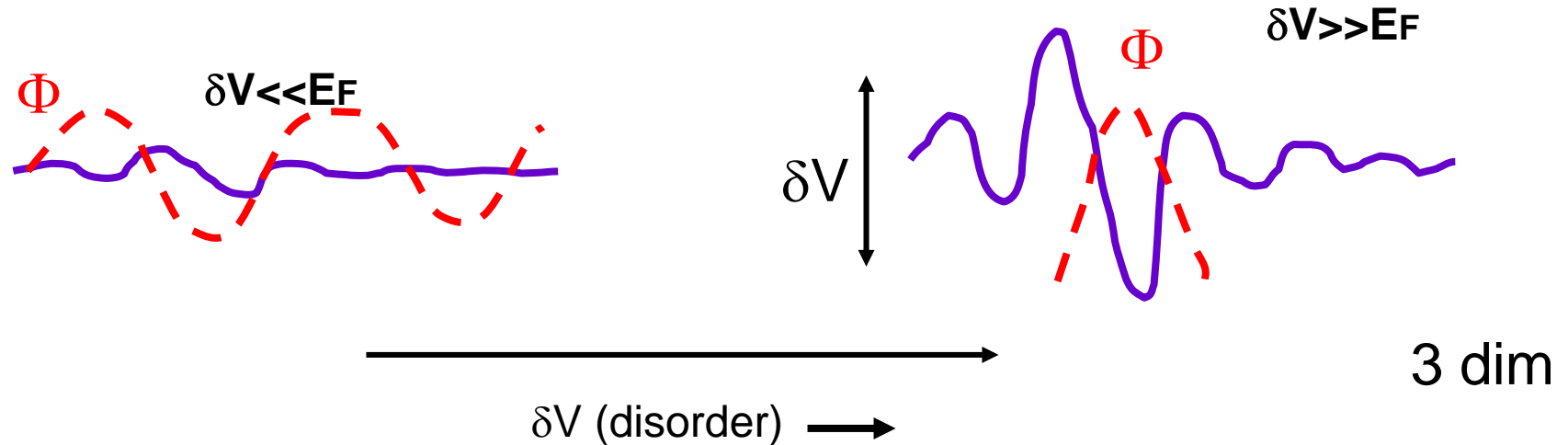
Main questions: nature of phases and excitations;  
nature of phase transitions

# Simplest disorder driven quantum phase transition

## Anderson Localization (1958)

non interacting electrons  
in a random potential

$$H = p^2 / 2m + V(r)$$



CONDUCTOR

ANDERSON INSULATOR

**Extended** wave function  
Sensitive to boundary conditions

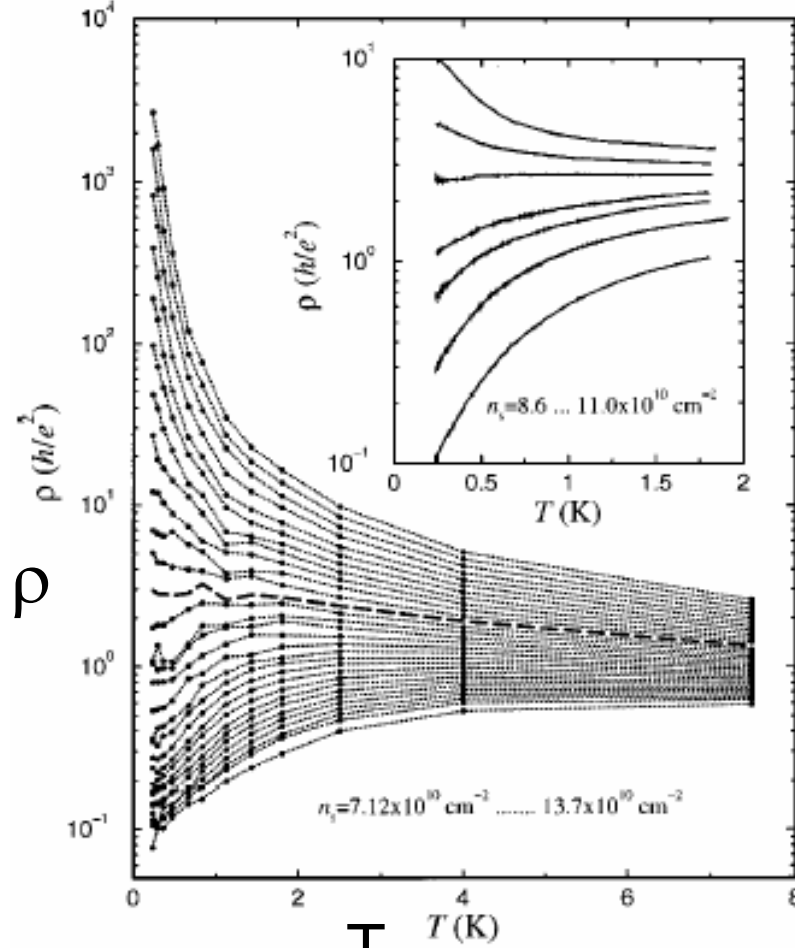
**Localized** wave function  
Insensitive to boundaries

2d: All states are localized; No true metals in 2d

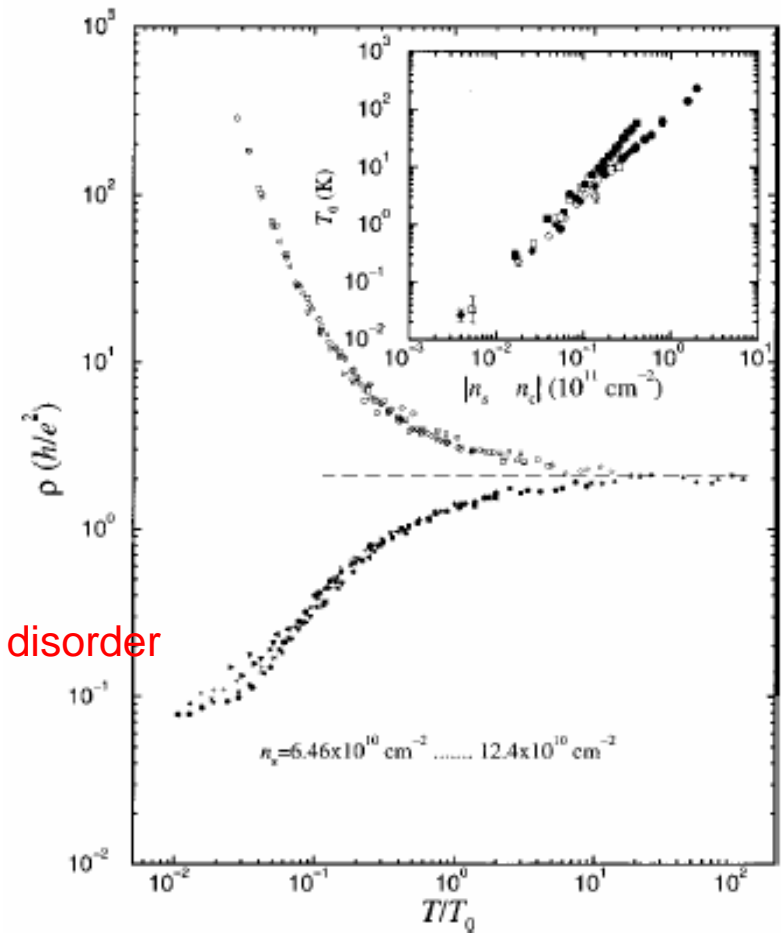
(Abrahams et.al PRL 1979)

INSULATOR

# METALS IN 2D ?



“METAL”



disorder

EXPERIMENTS

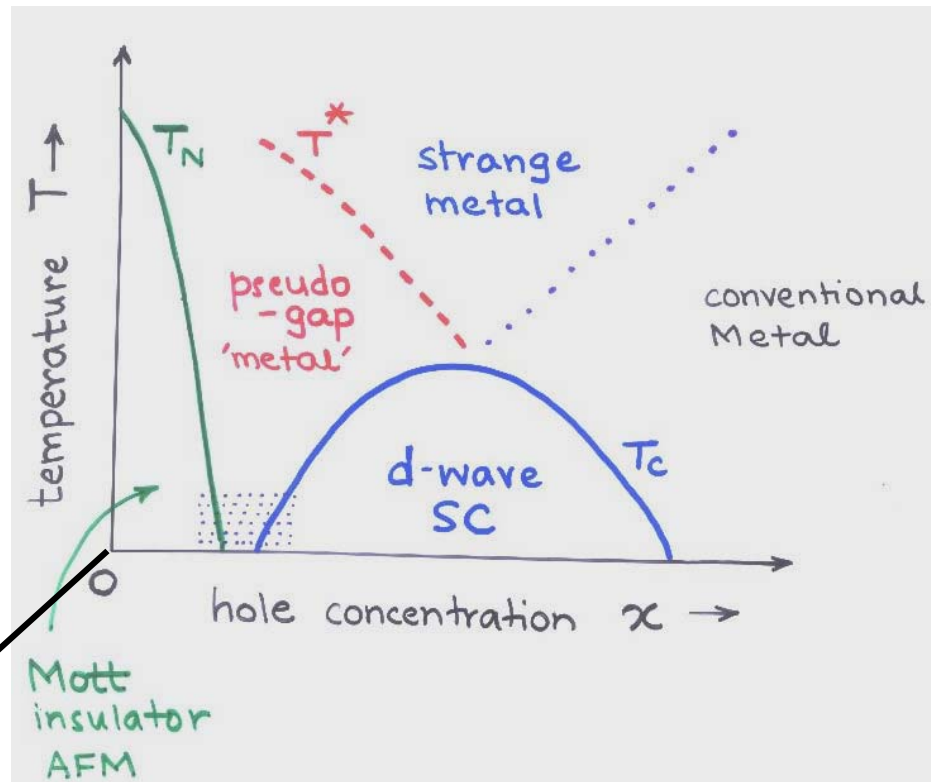
E. Abrahams, S. Kravchenko, M. Sarachik  
Rev. Mod. Phys. 73, 251 (2001)

In condensed matter systems interactions  
cannot be ignored;  
By localizing particles,  
disorder only enhances the interactions

repulsive interactions: superfluids (bosons)  
metals (fermions)

attractive interactions: superconductors (fermions)

# Effect of Disorder on a Mott Insulator



## MAIN QUESTION:

What is the effect of disorder on  
AFM long range order?

on charge gap?

Which is killed first?

Or are they destroyed together...

# Model: Hubbard model + potential disorder

$H =$  Kinetic energy

$$-t \sum_{\langle i,j \rangle \sigma} c_{i\sigma}^{\dagger} c_{j\sigma} + h.c.$$

$d=2$

+

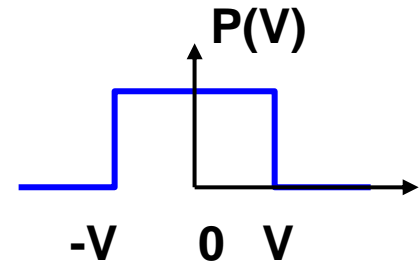
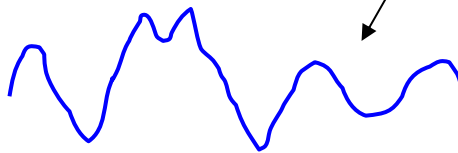
Repulsion

$$+U \sum_i n_{i\uparrow} n_{i\downarrow}$$

+

Random potential

$$+ \sum_i (V_i - \mu) n_i$$



$$\langle n \rangle = 1$$

$V=0$  Mott insulator with finite charge gap and long range AFM order

$U=0$  localization problem of non-interacting electrons



## Techniques:

No small parameter – need NONPERTURBATIVE methods

Field theoretic techniques for clean systems

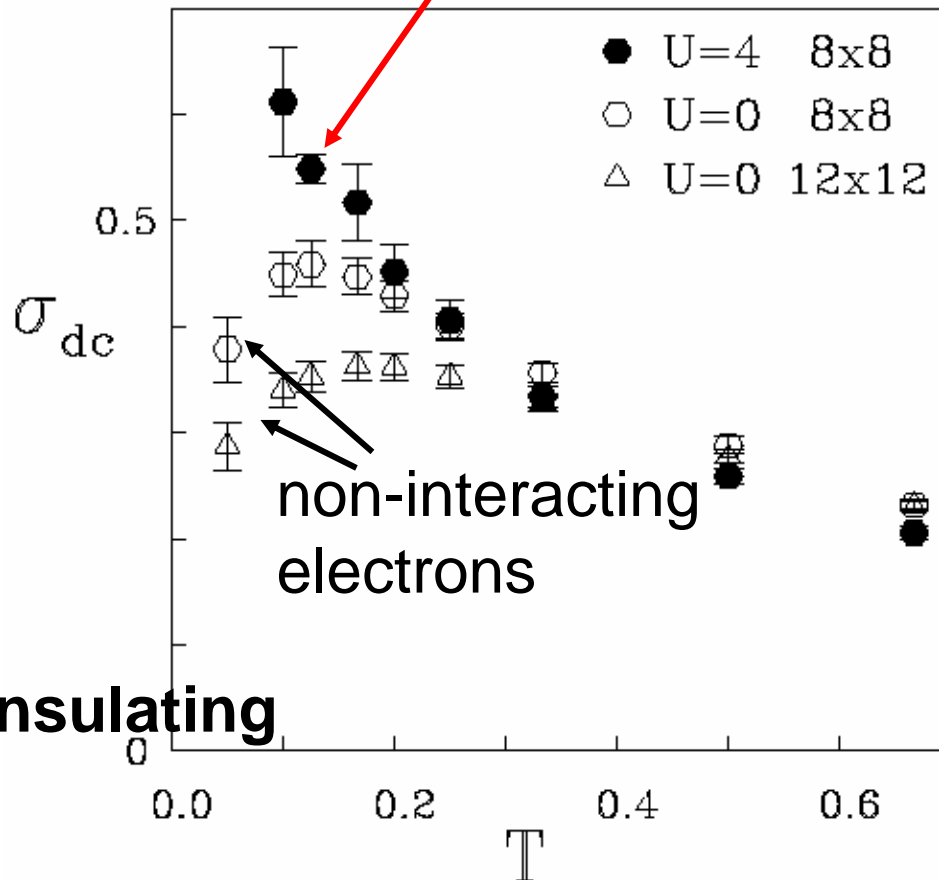
(Sachdev, “Quantum Phase Transitions”)

## Disordered Systems:

- numerical Quantum Monte Carlo techniques
- inhomogeneous mean field methods
- sum rules and bounds

# INTERACTING ELECTRONS WITH DISORDER IN 2D

Interacting  
electrons



Interplay of interactions and disorder enhance conductivity

Can it drive the system metallic?

Technique:  
Coherent state path integral  
for fermions

Sign problem at low  $T$

# INHOMOGENEOUS MEAN FIELD THEORY

- STRENGTH OF INTERACTION  $U$
- DENSITY OF ELECTRONS
- DISORDER PROFILE (RANDOM POTENTIAL)

**INPUT**

**MFT** 
$$h^+(r) = -|U| \langle c_{r\uparrow}^\dagger c_{r\downarrow} \rangle \quad h^-(r) = -|U| \langle c_{r\downarrow}^\dagger c_{r\uparrow} \rangle \quad \langle n_{i\sigma} \rangle$$

**2NX2N matrix**

$$\begin{pmatrix} \hat{K}_\uparrow & \hat{h}^- \\ \hat{h}^+ & \hat{K}_\downarrow \end{pmatrix} \begin{pmatrix} \psi_{n\uparrow} \\ \psi_{n\downarrow} \end{pmatrix} = \epsilon_n \begin{pmatrix} \psi_{n\uparrow} \\ \psi_{n\downarrow} \end{pmatrix}$$

$$\hat{K}_\sigma \psi_{n\sigma}(r) = -t \sum_\delta \psi_{n\sigma}(r + \delta) + [V(r) - \tilde{\mu}_\sigma(r)] \psi_{n\sigma}(r)$$

$$h^\sigma \psi_{n\sigma}(r) = h^\sigma(r) \psi_{n\sigma}(r)$$

• pick some  $\{h^\pm(r)\}$  and  $\{n_\sigma(r)\}$

$$\tilde{\mu}_\sigma(r) = U(1/2 - n_{\bar{\sigma}}(r))$$

• solve MF equations and get  $\epsilon_n, \psi_{n\sigma}(r)$

• determine  $h^+(r) = -U \sum_n \psi_{n\uparrow}^*(r) \psi_{n\downarrow}(r)$

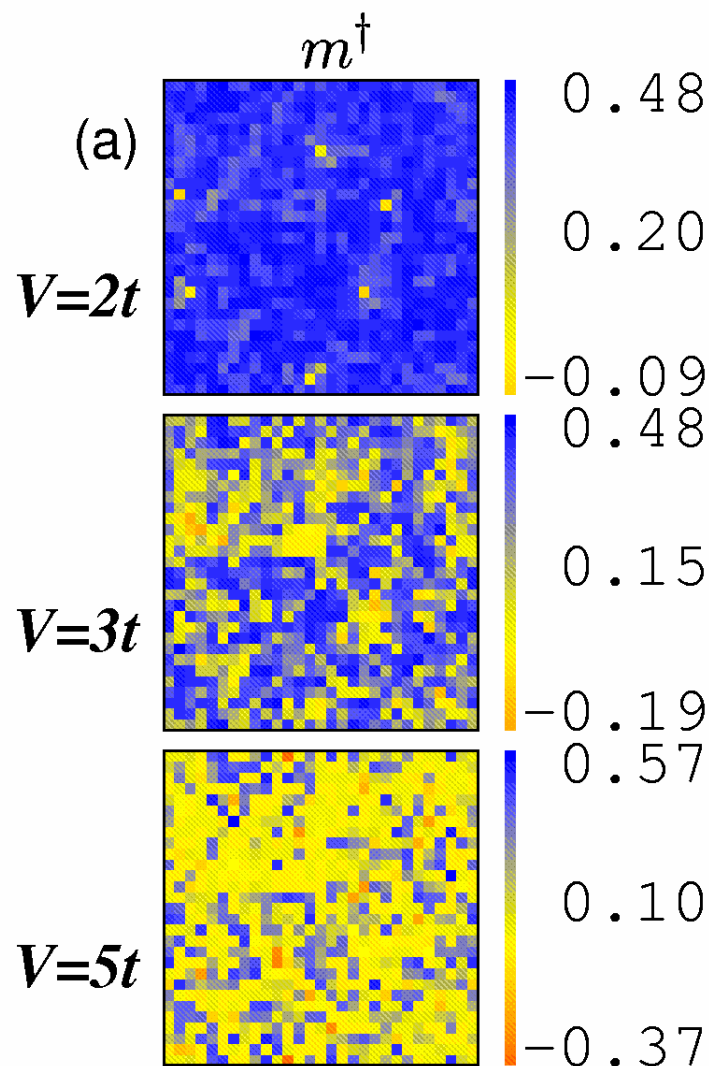
$$n_\sigma(r) = \sum_n |\psi_{n\sigma}(r)|^2$$

**SELF CONSISTENCY**

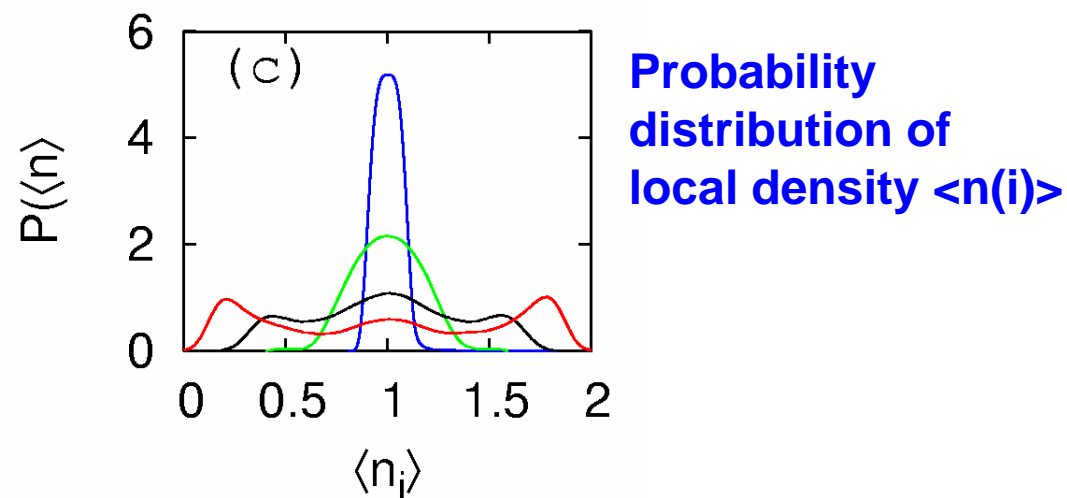
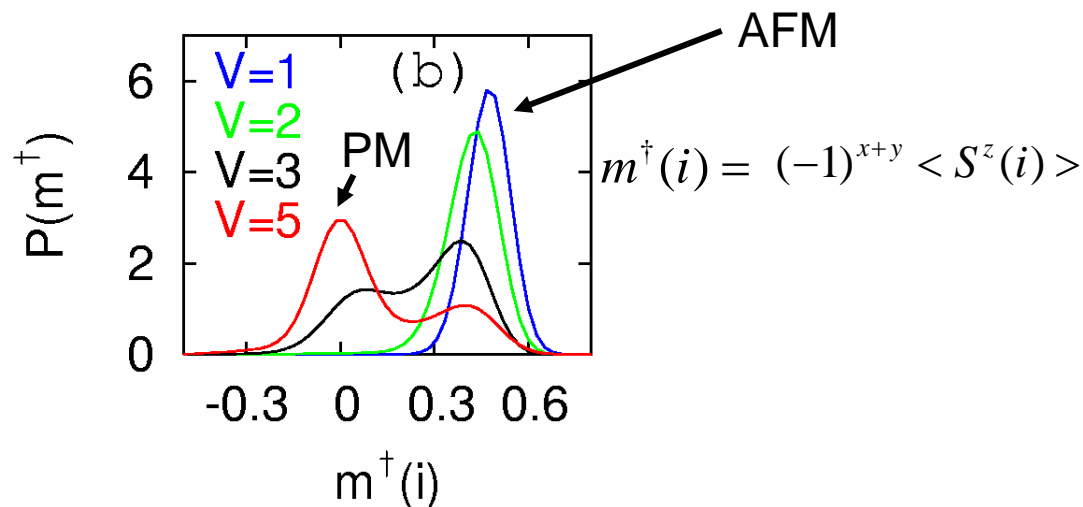
iterate until self consistency is achieved at EACH site

Broyden method

$$(-1)^{i_x+i_y} \langle S_z(i) \rangle$$



## Probability distribution of local staggered magnetization



$N=24 \times 24$   $U=4t$   $T=0$   $n=1$   
 averaged over 10 realizations

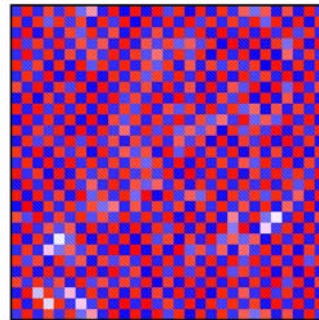
# DISORDERED HUBBARD MODEL AT HALF FILLING

Local magnetization

$$\langle S_z(i) \rangle$$

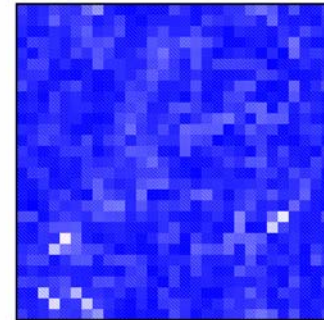
$$(-1)^{i_x+i_y} \langle S_z(i) \rangle$$

N=24x24  
U=4t



V=2t

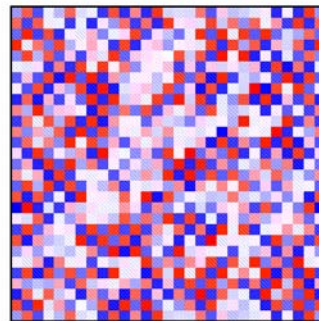
(a)



0.48

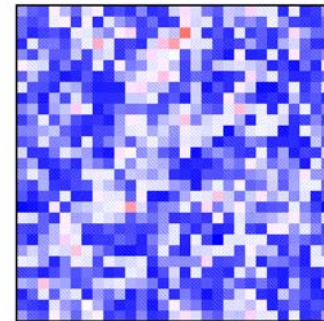
0.23

-0.02



V=3t

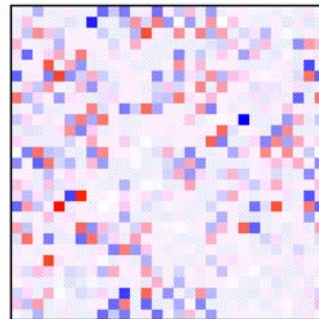
(b)



0.49

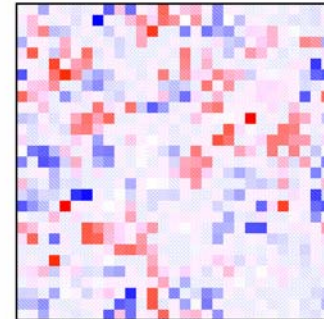
0.09

-0.30



V=5t

(c)



0.73

-0.03

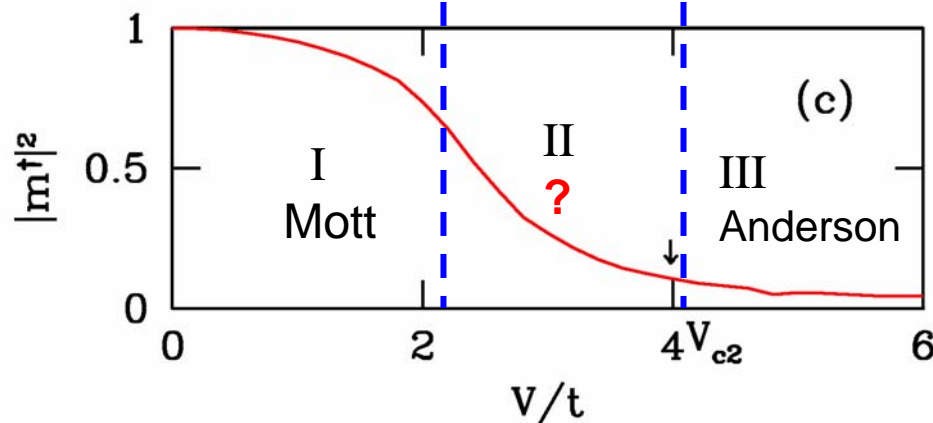
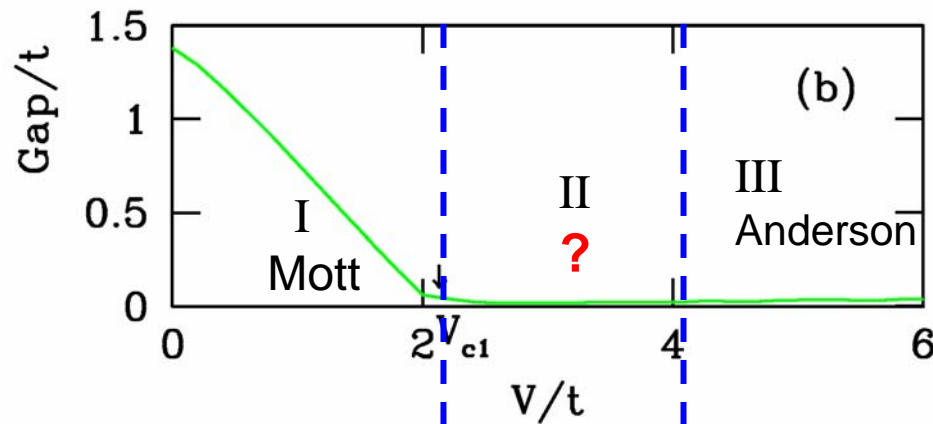
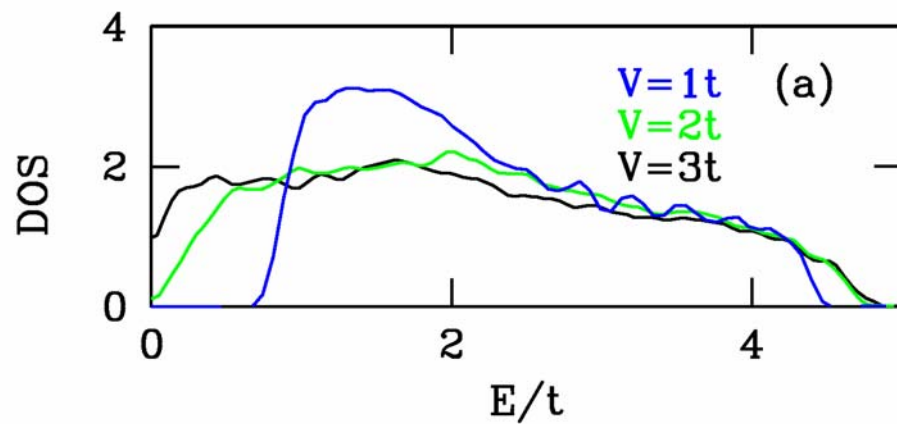
-0.79

Disorder V:

uniform distribution  
couples to density

As disorder strength increases the defected regions i.e. regions with suppressed checker board pattern grows

D. Heidarian and NT  
PRL 93, 126401 (2004)

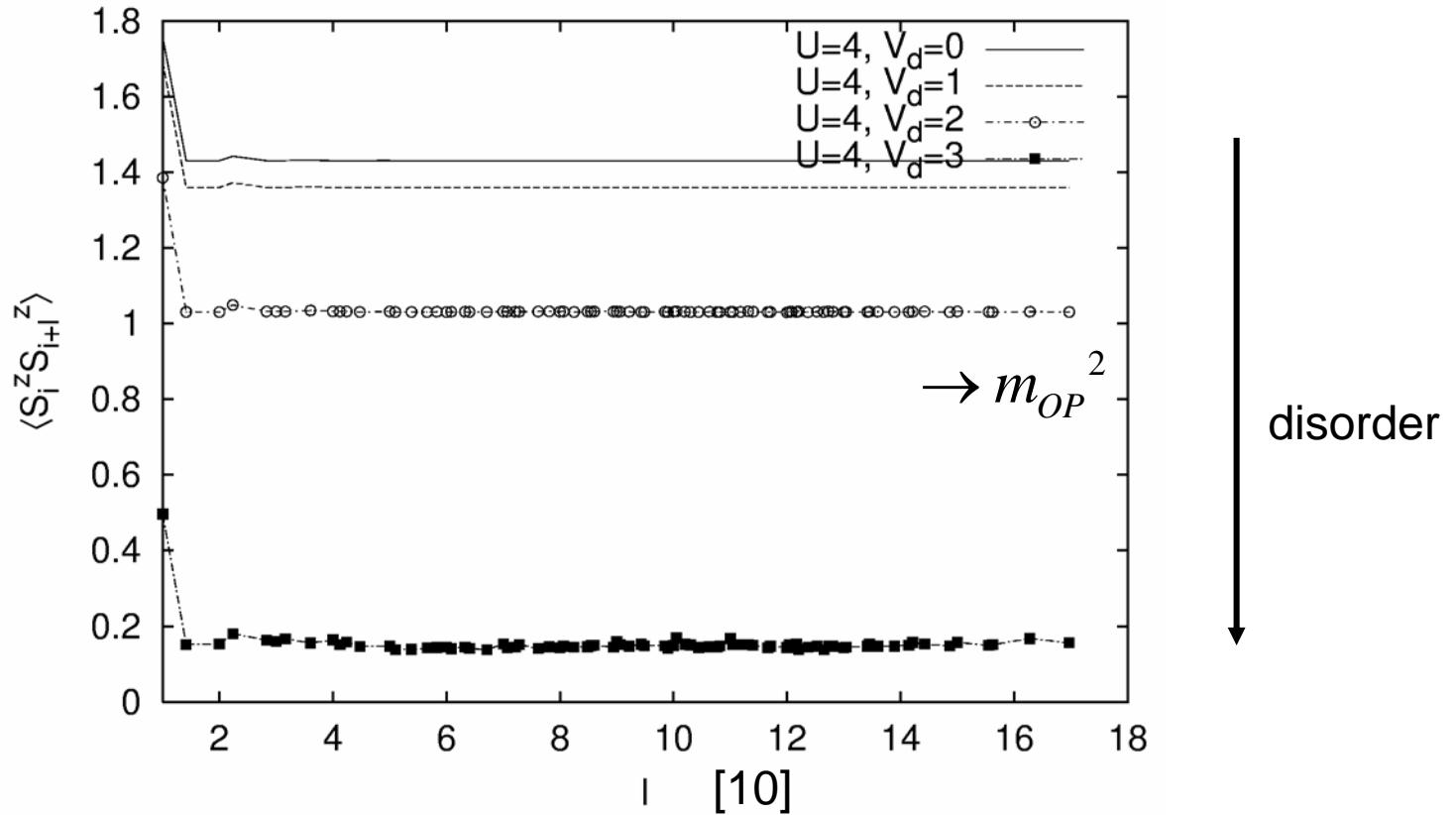


$$\text{Gap} \sim U$$

$$\text{AFM } J \sim t^2 / U \ll U$$

- Why is the gap killed first?
- What is the ? phase?

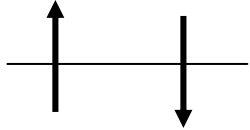
## spin-spin correlation function



$m_{OP}$  =order parameter

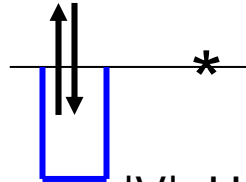
# CONNECTIONS WITH PERCOLATION (t=0)

singly occupied sites

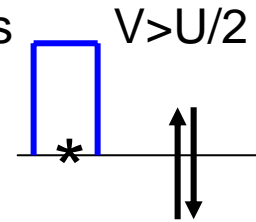


Contribute to AFLRO

doubly occupied and empty sites



$|V| > U/2$

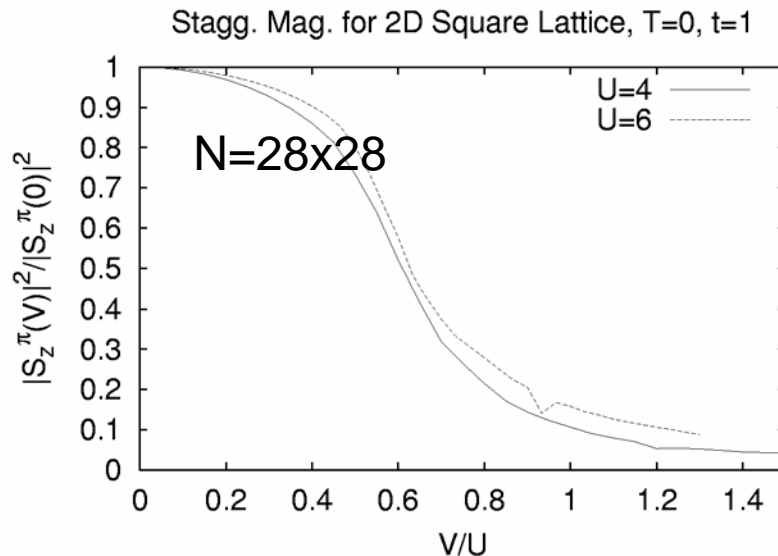


$V > U/2$

Destroy AFLRO

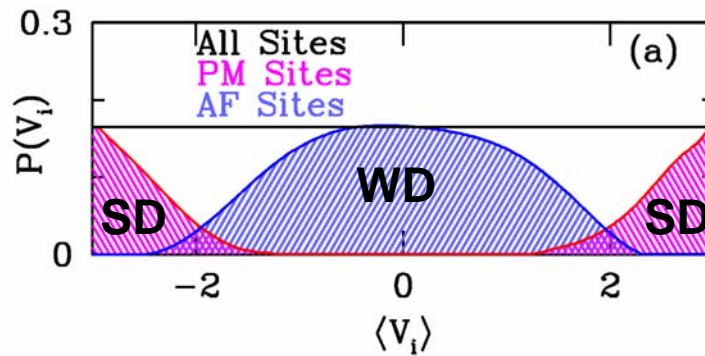
Classical percolation of vacancies on square lattice  $p_{crit} = 0.41$

$$\text{Probability of 'bad sites'} \Rightarrow 1 - \frac{U/2}{V} \equiv p_{crit} \Rightarrow \left( \frac{V}{U} \right)_{crit} = \frac{1}{2(1 - p_{crit})} = 0.85$$

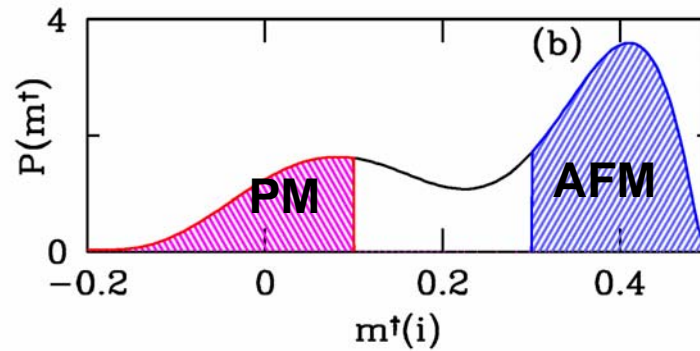


SW



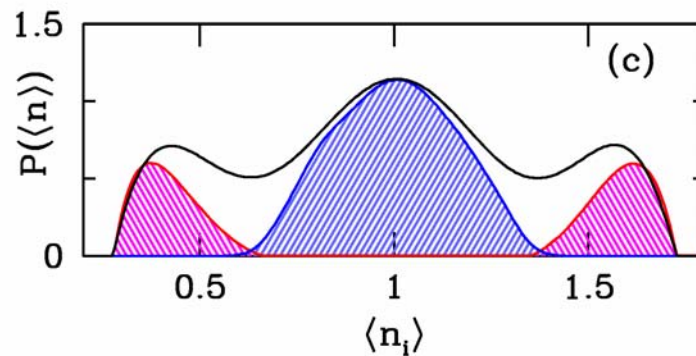


WD: weakly disordered  
SD: strongly disordered

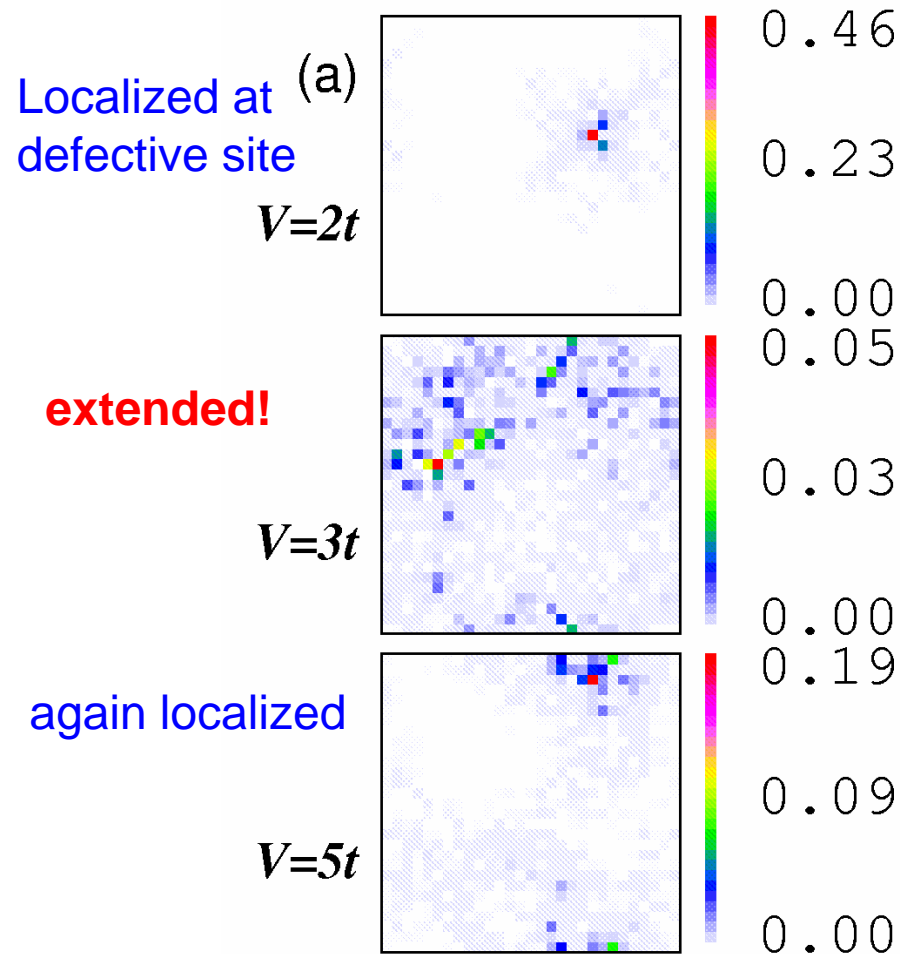


Correlation of AFM regions with WD  
and  $\langle n \rangle \sim 1$

PM regions with SD and bimodal  $\langle n \rangle$



# NATURE OF EIGENFUNCTIONS AROUND THE FERMI ENERGY

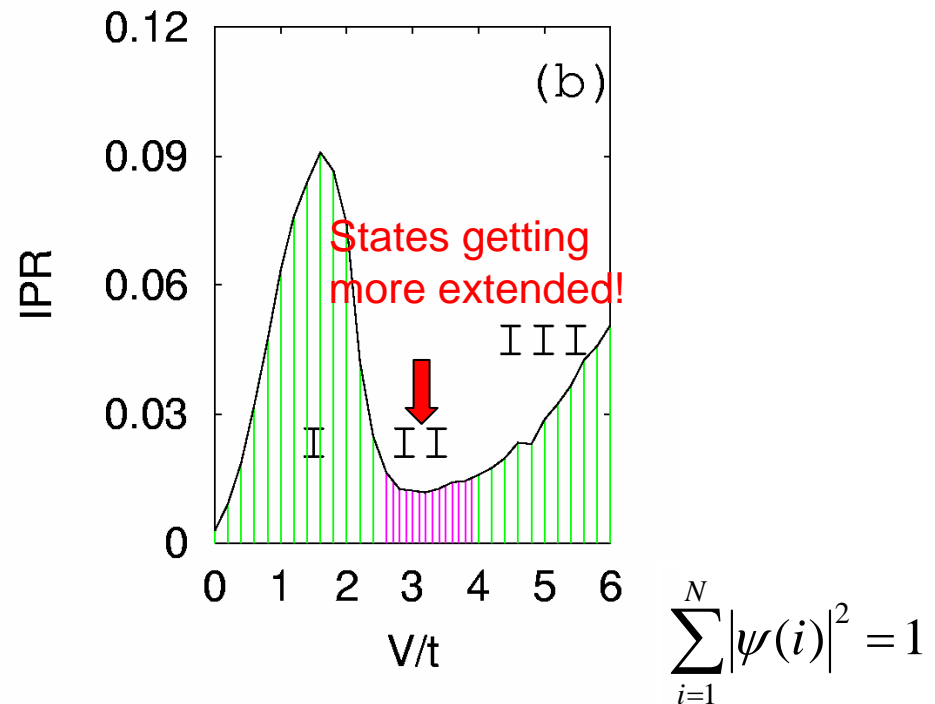


**Extended state:**

**Localized state:**

Inverse participation ratio

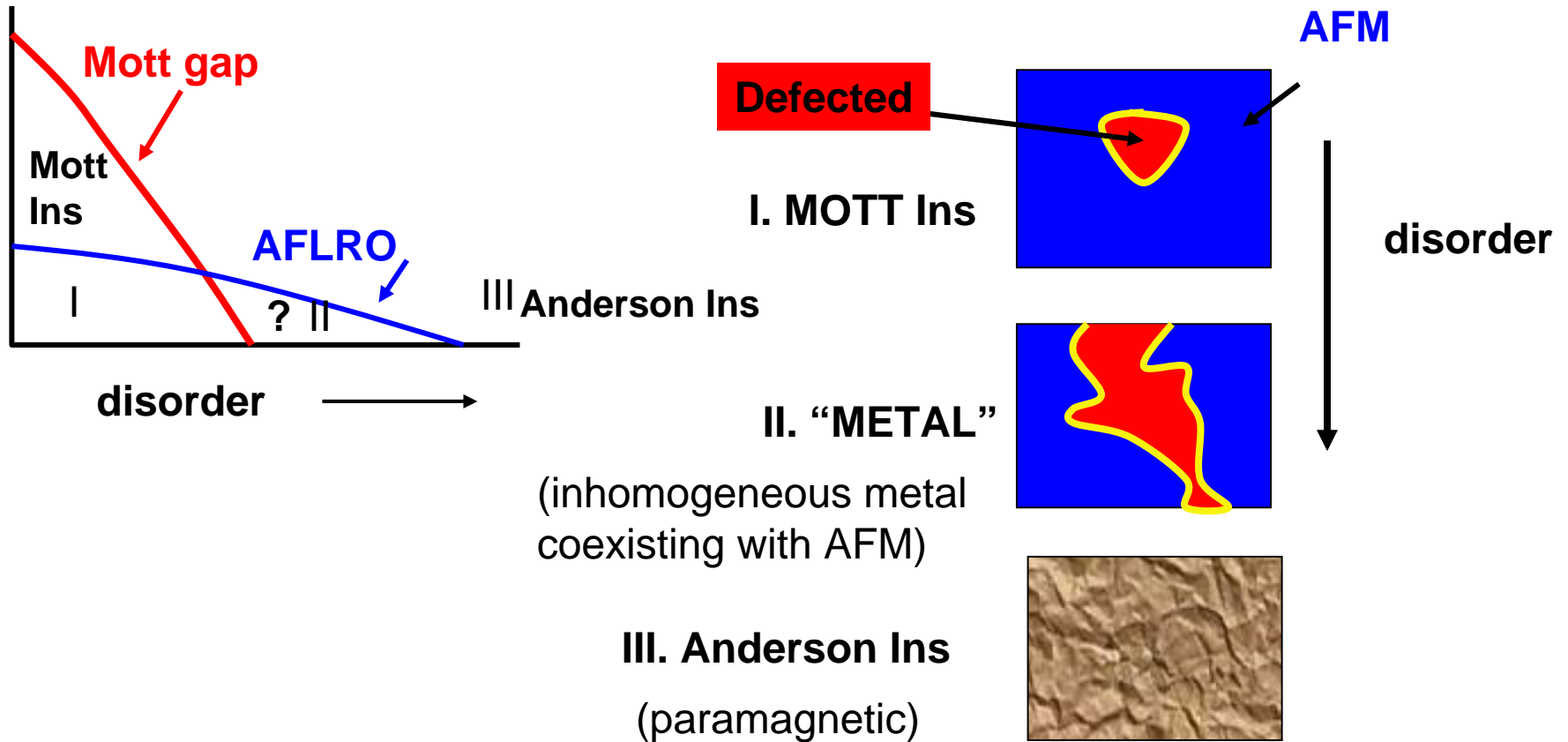
$$IPR = \sum_{i=1}^N |\psi(i)|^4 \sim 1/\xi^2$$



$$\psi(i) \propto 1/\sqrt{N} \quad IPR \sim 1/N$$

$$\psi(i_0) \propto 1 \quad IPR \sim 1$$

# CONCLUSIONS



## II. Anomalous metallic state:

- states live in the defected region
- get more extended with increasing disorder
- percolating metallic regions coexist with AFM regions...

# GENERAL CONCLUSIONS

**NANOSCALE inhomogeneities** induced by disorder

**SELF ORGANISATION** of system into regions of relatively high disorder and regions of low disorder

**GENERIC BEHAVIOR** seen in quantum Hall systems, manganites, superconductors and Mott insulators

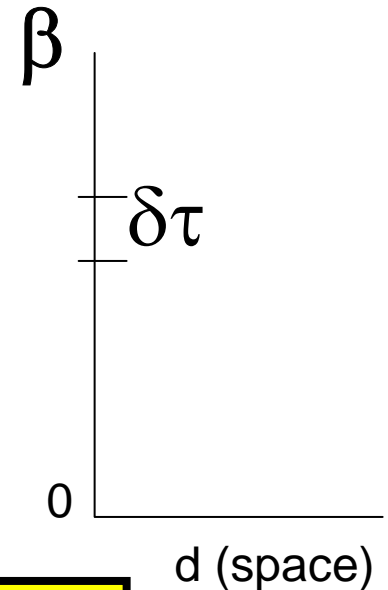
**LOCAL PROBES** to see charge, spin and superconductivity  
(STM, STS, spin polarized tunneling, Josephson tunneling...)

# Coherent state path integral Monte Carlo: Basic idea

$$H_{Hubbard} = -t \sum_{\langle i,j \rangle \sigma} c_{i\sigma}^\dagger c_{j\sigma} + U_0 \sum_i n_{i\uparrow} n_{i\downarrow} \equiv K + U$$

$$e^{-\beta H} = \left[ e^{-\delta\tau H} \right]^L \cong \left[ e^{-\delta\tau K} e^{-\delta\tau U} \right]^L$$

$$U_0 n_{i\uparrow} n_{i\downarrow} \rightarrow S_{i\tau} (n_{i\uparrow} - n_{i\downarrow})$$



$$Z = \text{Tr} e^{-\beta(H-\mu N)} = \sum_{\{S\}} \text{Tr} \prod_{\tau\sigma} e^{-\delta\tau \sum_{i,j} c_{i\sigma}^\dagger h(\tau,\sigma) c_{j\sigma}}$$

$$Z = \sum_{\{S\}} \det M_\uparrow(S) M_\downarrow(S)$$

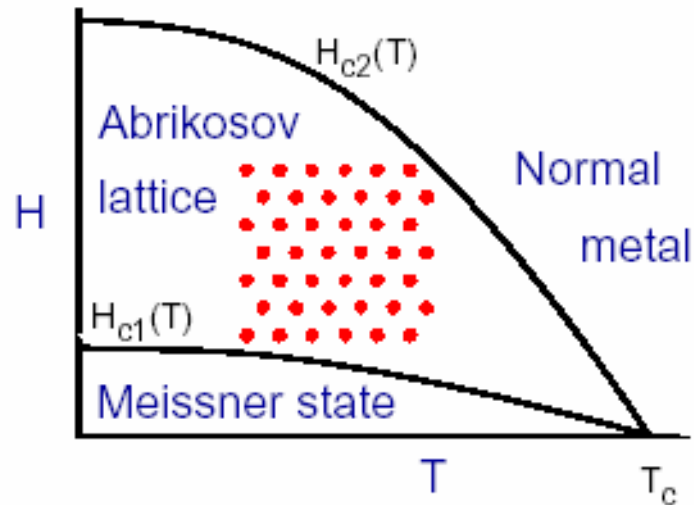
$$M_\sigma(\{S\}) = \left[ I + \prod_\tau e^{-\delta\tau h(\tau,\sigma)} \right]$$

VMC variational	GPMC Green function	PIMC Path integral	DMC Determinantal
$T=0$	$T=0$	$T \neq 0$	$T \neq 0$
$\Psi_{trial}$	$\Psi_{GS}$	$Z = Tr \hat{\rho}(\beta)$	$Z = \sum Det(M_{\uparrow}) Det(M_{\downarrow})$
Wave function dependent Easy to apply	“exact” for bosons; mixed estimator	“exact” for bosons	can be “exact” for some fermion problems also
$ \Psi ^2$ sampled  NO sign problem	SIGN PROBLEM FOR FERMIONS		
	Nodes in w.f --fixed node Release node	$(-1)^P$ Cancellation of amplitudes for fermions	sign absorbed in operator; divergence of $\langle sign \rangle$ at low T
Results only as good as input wave function BUT....	trial state must have non-zero overlap with true ground state	no aprior inputs required  Disorder YES	No apriori inputs  Disorder YES
		Analytic continuation to get finite frequency	

# **STUDYING CLASSICAL PHASE TRANSITIONS WITH QUANTUM MONTE CARLO TECHNIQUES!!**

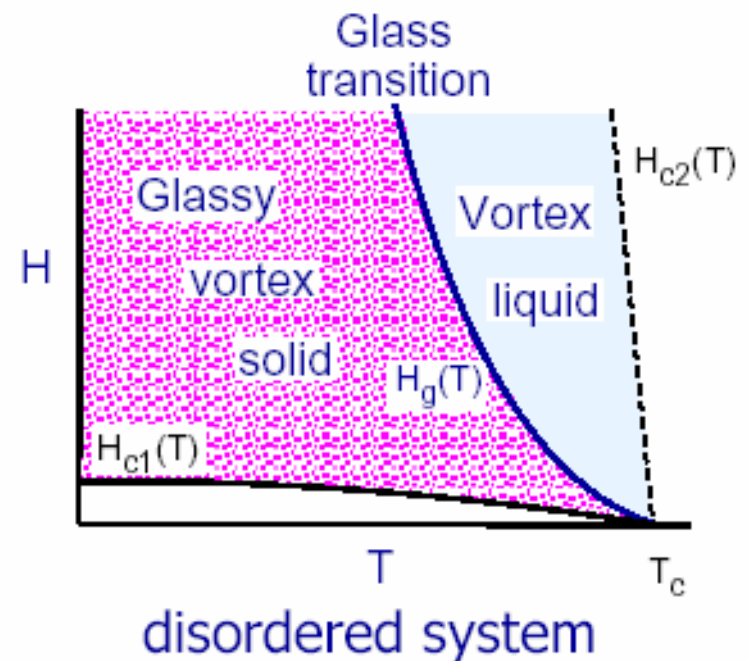
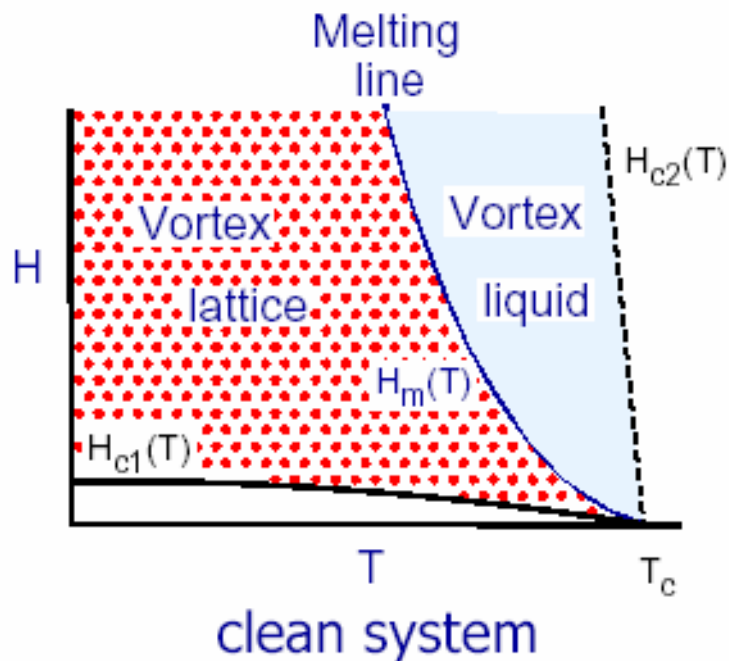
**VORTICES**

Conventional  
superconductors:  
(type II)

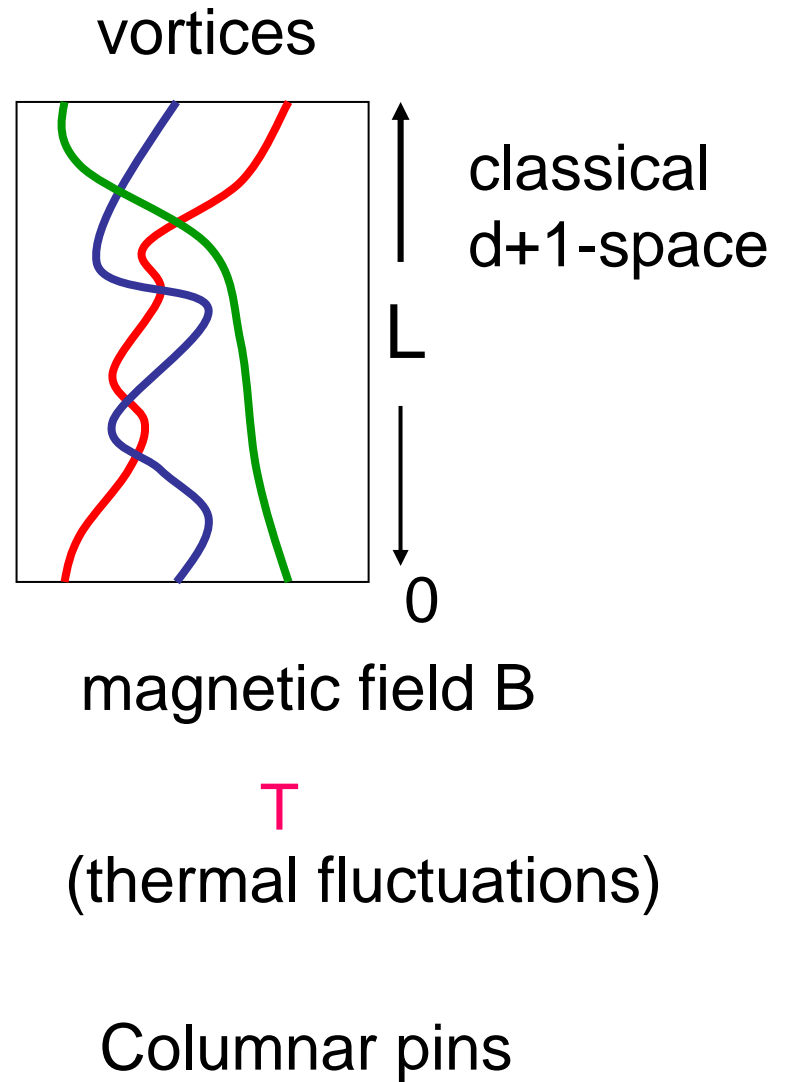
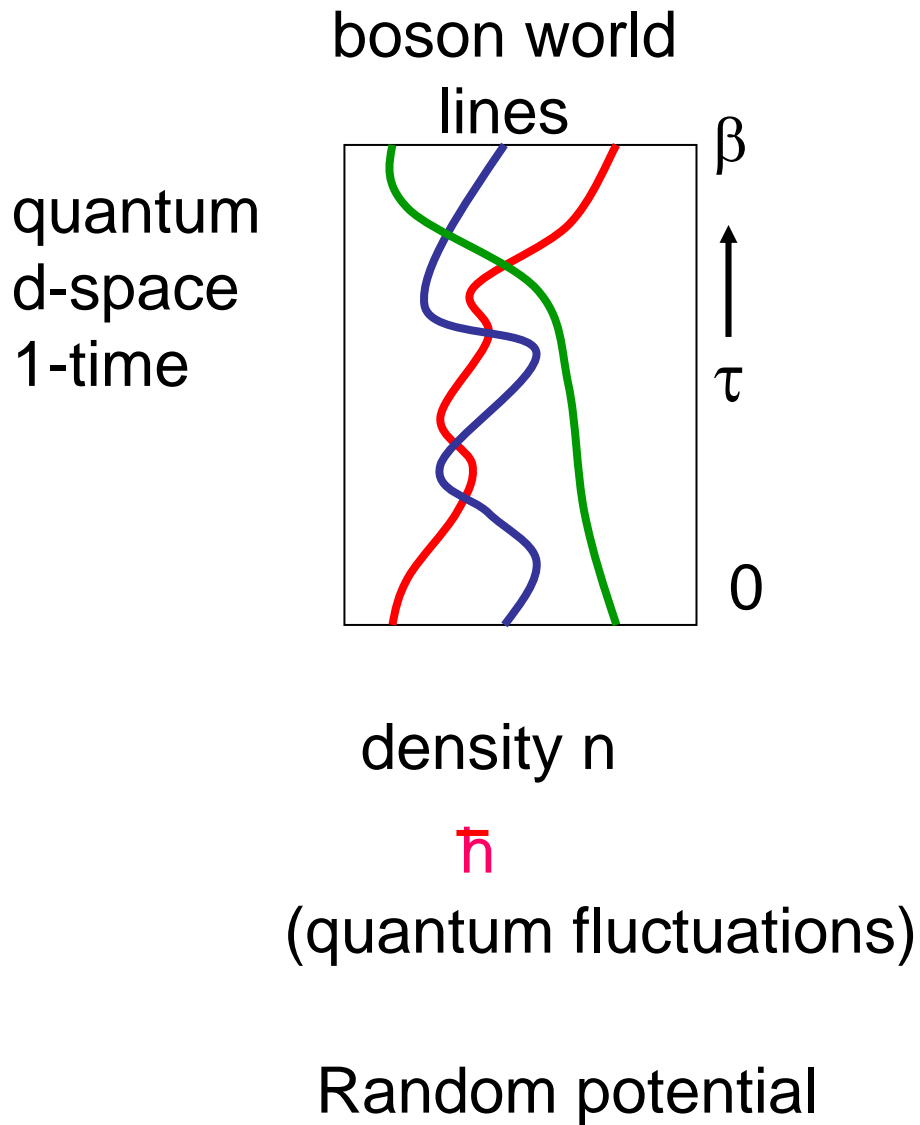


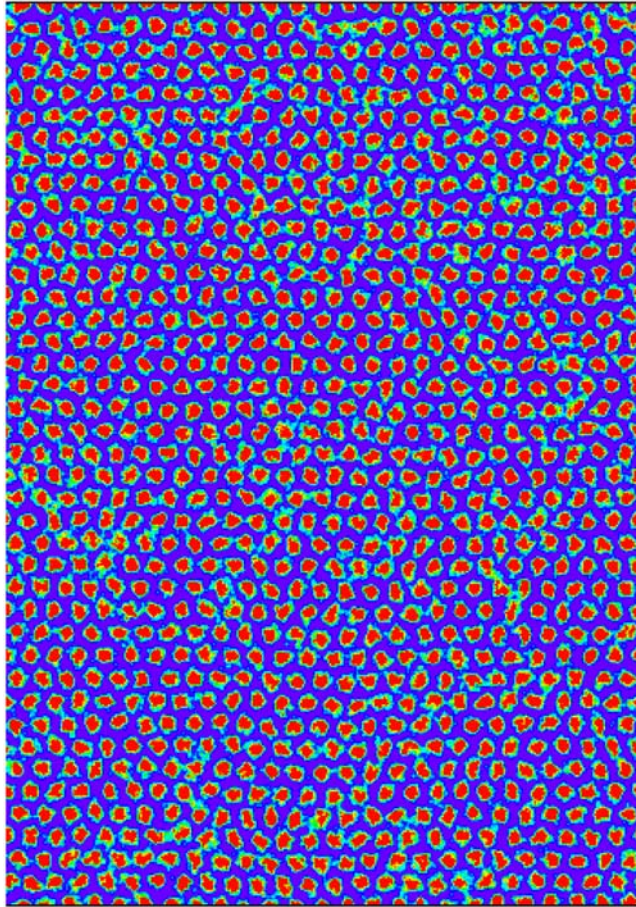
High-temperature superconductors:

(layered SC, high  $T_c$ , fluctuations)

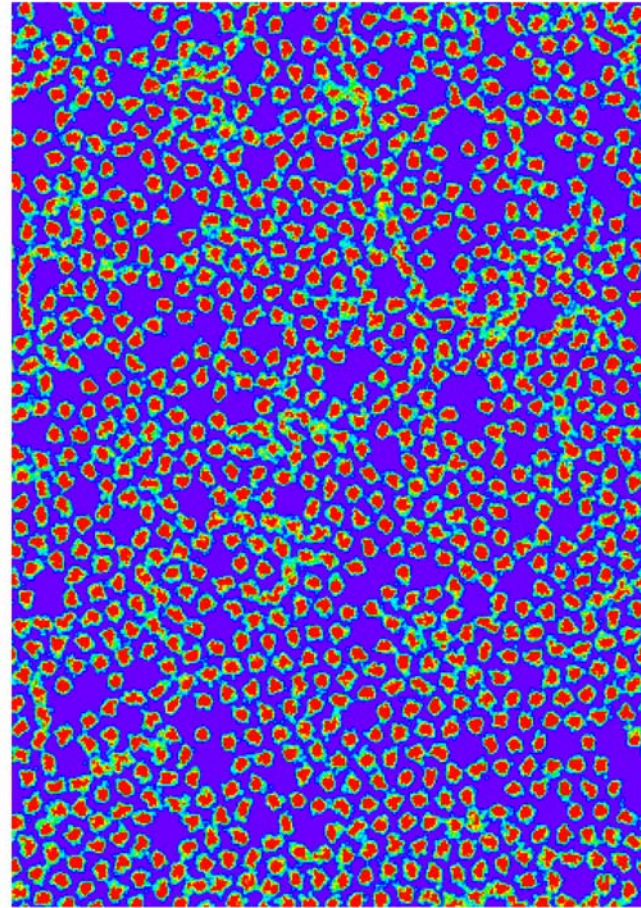








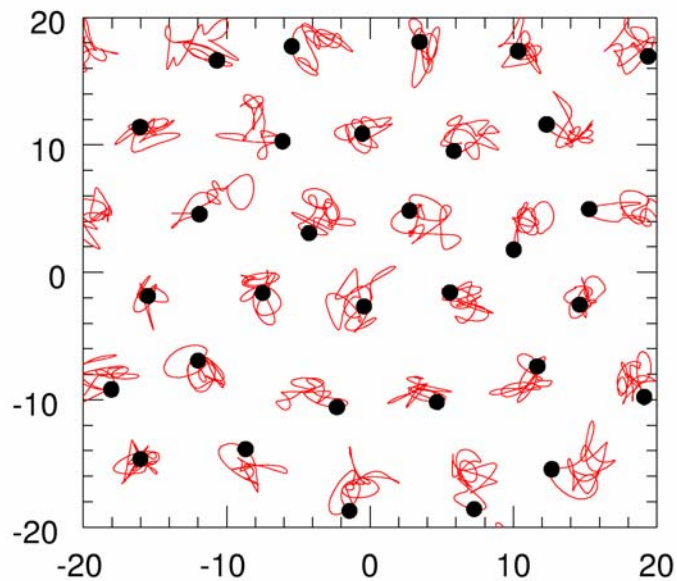
(a)



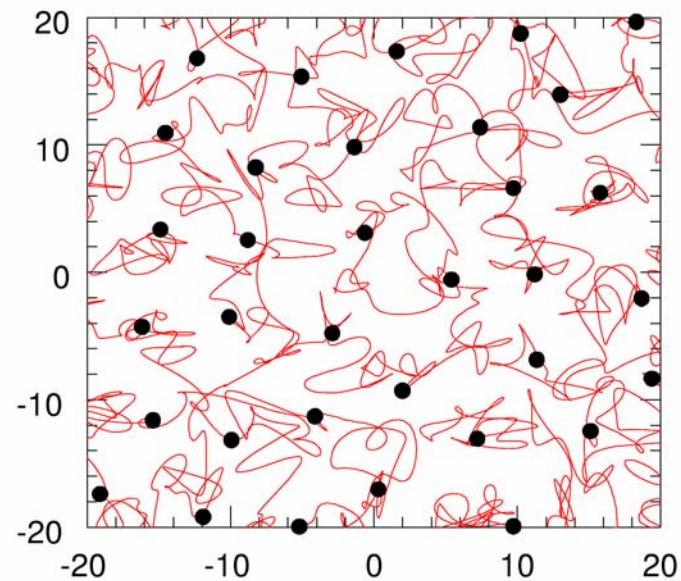
(b)

P. Sen, N. Trivedi, D.M. Ceperley, PRL **86**, 4092 (2001).

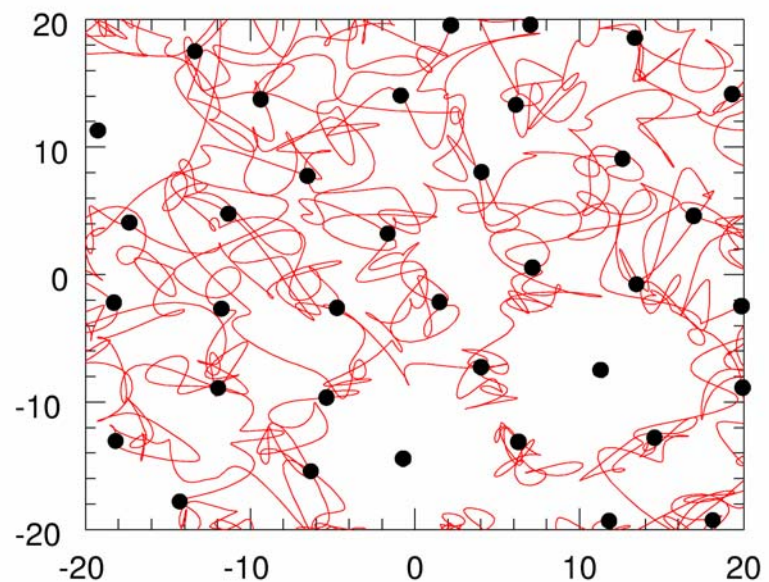




$\Lambda=0.045(\text{clean})$



$\Lambda=0.065(\text{clean})$



$\Lambda=0.065(\text{with pins})$

## Lattice models

### Examples:

Quantum magnetism:

**Heisenberg antiferromagnet**

Strongly interacting bosons:  
atoms in traps; optical lattices:

**+U Bose Hubbard model**

Feshbach resonance: BCS-BEC crossover:

**-U Fermion Hubbard Model**

High temperature superconductivity:

**+U Fermion Hubbard model**

Quantum Hall Effect:

### Disorder driven Quantum Phase transitions

Superfluid—Bose Glass transition:  
(Josephson Junction arrays; helium in aerogels)

**+U Bose Hubbard model +  
disorder**

Superconductor-Insulator Transition:  
(ultra thin films; high  $T_c$  SCs)

**-U Fermion Hubbard model  
+ disorder**

Metal-Insulator transition:  
(disordered Mott insulators; 2D electron gases)

**+U Fermion model +  
disorder**